TVS Diodes





Description

The SPCL1 series of high power TVS diode is specially designed for meeting severe surge test environment of both AC and DC line protection applications. It features a very fast response and ultra low clamping characteristics over traditional metal oxide varistor (MOV) solutions. They can be connected in series and / or parallel to create a very high surge current protection solution.

Applications

- Communication Equipment
- Security & Protection
- Industrial Control Equipment
- **Power Supply**
- **Automotive Electronics**
- **New Energy**
- Lightning Protection

Features

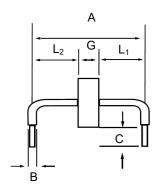
- Very low clamping voltage
- Sharp breakdown voltage
- Low slope resistance
- Bi-directional
- IEC-61000-4-2 ESD 30 kV (Air), 30 kV (Contact)
- Symmetric in leads width for easier soldering during assembly
- ESD protection of data lines in accordance with IEC 61000-4-2
- EFT protection of data lines in accordance with IEC 61000-4-4
- Halogen-free
- RoHS compliant
- Glass passivated junction
- Pb-free E4 means 2nd level interconnect is Pb-free and the terminal finish material is Silver

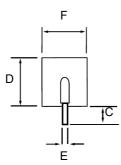
Functional Diagram





Package Outline Dimensions





	Symbol	Millimeters	Inches			
	Α	24.15 ± 1.00	0.950 ± 0.040			
	В	2.5 ± 0.60	0.100 ± 0.024			
	С	6.00 ± 1.00	0.236 ± 0.039			
	D	14.48 max.	0.570 max.			
	E	1.270 ± 0.05	0.050 ± 0.002			
	F	12.70 max.	0.500 max.			
-	G-066C / 076C	2.44 ± 1.00	0.096 ± 0.040			
	G-190C	4.80 ± 1.00	0.189 ± 0.040			
	G-380C / 430C	5.60 ± 1.00	0.220 ± 0.040			
	L1 / L2	L1 = L2 tolerance ± 1.0 mm (0.04 inch)				

Maximum Ratings and Thermal Characteristics

(T_A = 25 °C unless otherwise specified.)

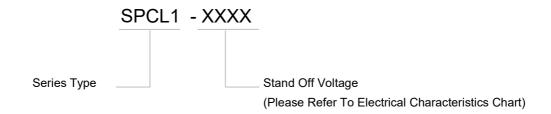
Parameter	Symbol	Value	Unit
Operating Storage Temperature Range	T _{STG}	-55 to 150	°C
Operating Junction Temperature Range	TJ	-55 to 125	°C
Current Rating (Note 1)	I _{pp}	1	kA

Note

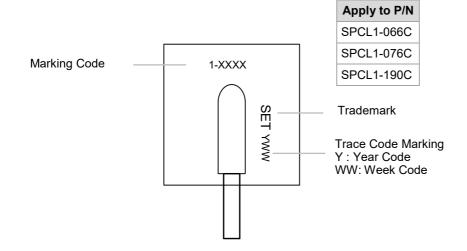
1. Rated I_{PP} measured with 8/20 μs pulse.



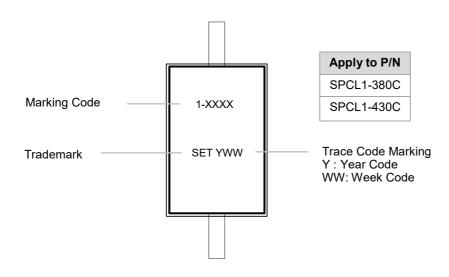
Part Numbering System



Marking



Type 1 - Side View



Type 2 - Top View



Glossary

Item	Description				
	Clamping Voltage				
V _C	Voltage across TVS in a region of low differential resistance that serves to limit the voltage across the device terminals.				
	Reverse Stand-off Voltage				
V _R	Maximum voltage that can be applied to the TVS without operation.				
VK	NOTE : It is also shown as V_{WM} (maximum working voltage (maximum d.c. voltage)) and known as rated stand-				
	off voltage (V_{so}) .				
	Reverse Leakage Current				
I _R	Current measured at $V_{\rm R}$				
	NOTE : Also shown as I _D for stand-by current.				
V BR	Breakdown Voltage				
	Voltage across TVS at a specified current I _T in the breakdown region.				
I _{PPM}	Rated Random Recurring Peak Impulse Current Maximum-rated value of random recurring peak impulse current that may be applied to a device.				
	Rated Average Power Dissipation				
P _{M(AV)}	Maximum-rated value of power dissipation resulting from all sources, including transients and standby current,				
- W(AV)	averaged over a short period of time.				
	Rated Random Recurring Peak Impulse Power Dissipation				
P PPM	Maximum-rated value of the product of rated random recurring peak impulse current (I_{PPM}) multiplies by specified				
	maximum clamping voltage ($V_{\mathbb{C}}$).				
C _J	Capacitance				
	Capacitance across the TVS measured at a specified frequency and voltage.				
	Peak Forward Surge Voltage				
V _{FS}	Peak voltage across an TVS for a specified forward surge current (I _{FS}) and time duration.				
	NOTE : Also shown as V_{F}				
,	Forward Surge Current				
I _{FS}	Pulsed current through TVS in the forward conducting region. NOTE: Also shown as I_{F} .				
α _{V(BR)}	Temperature Coefficient of Breakdown Voltage The change of breakdown voltage divided by the change of temperature.				
	Peak pulse Current				
I _{PP}	Peak pulse current value applied across the TVS to determine the clamping voltage $V_{\mathbb{C}}$ for a specified wave shape.				
	Pulsed D.C. Test Current Test current for measurement of the breakdown voltage V_{BR} . This is defined by the manufacturer and usually				
/ ⊤	given in milliamperes with a pulse duration of less than 40 ms.				
	NOTE : Also shown as I_{BR} .				

--(GB-T 18802.321 / IEC 61643-321 / JESD210A)

TVS Diodes

Transient Voltage Suppression Diodes

SPCL1 Series (1 kA)

Electrical Characteristics (T_A=25 °C unless otherwise noted)Table 1

Part Number	Device Marking Code	Break Volt V _{BR} (age	Test Current I _T	Stand-off Voltage V _R	Max. Reverse Leakage I _R @V _R	Typical I _R @85°C	Max. Clamping Voltage V _{CL} @ I _{pp} Peak Pulse Current		Max. Temp Coefficient OF V _{BR}	Max. Capacitance 0 Bias 10kHz
		Min	Max						_{PP}) te 1)		
		(\	")	(mA)	(V)	(μΑ)	(μΑ)	I _{PP} (A)	V _{CL} (V)	(%/°C)	(nF)
SPCL1 - 066C	1-066C	72	80	10	66	10	15	1,000	120	0.1	8.5
SPCL1 - 076C	1-076C	85	95	10	76	10	15	1,000	140	0.1	8.5
SPCL1 - 190C	1-190C	200	245	10	190	10	15	1,000	290	0.1	2.5
SPCL1 - 380C	1-380C	401	443	10	380	10	15	1,000	570	0.1	2.0
SPCL1 - 430C	1-430C	440	490	10	430	10	15	1,000	625	0.1	2.0

Note

Using $8/20 \mu S$ wave shape as defined in IEC 61000-4-5.



Ratings and Characteristic Curves (T_A =25 °C unless otherwise noted)

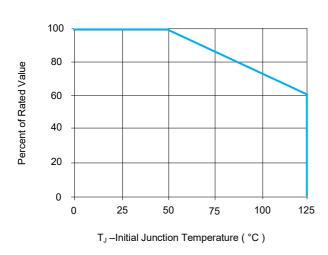


FIGURE 1 - Peak Power Derating

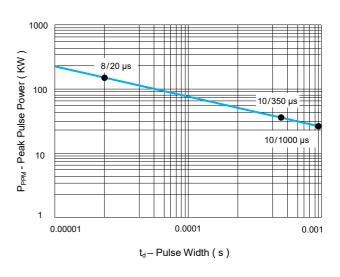


FIGURE 2 - Typical Peak Pulse Power Rating Curve

Ratings and Characteristic Curves (T_A =25 °C unless otherwise noted) (Continued)

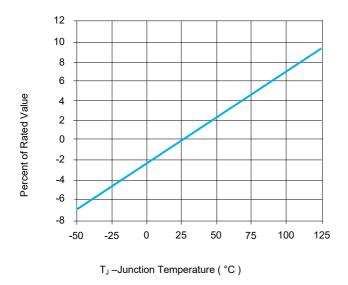


FIGURE 3 Typical VBR Vs Junction Temperature

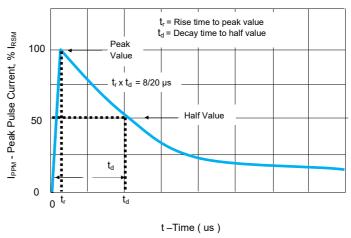


FIGURE 4 Pulse Waveform

Flow/Wave Soldering (Solder Dipping)

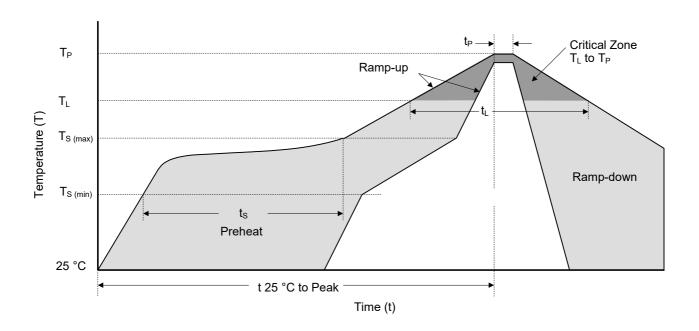
Peak Temperature :	260 °C +0 / -5 °C	
Dipping Time :	10 seconds	
Soldering :	1 time	

Physical Specifications

Weight	Contact manufacturer
Case	Epoxy encapsulated
Terminal	Silver plated leads, solderable per MIL- STD-750 Method 2026



Soldering Parameters



Reflowing Condition

Reflow Soldering	Lead-Free Assembly				
	Temperature Min (T _{S (min)})	150 °C			
Pre-heat	Temperature Max (T _{S (max)})	200 °C			
	Time (min to max) (t _s)	60 ~ 120 seconds			
Average Ramp Up Rate (L	Average Ramp Up Rate (Liquidus Temp (TL) to Peak				
T _S (max) to T _L	Ramp-up Rate	3 °C / second max.			
D (Temperature (T _L) (Liquidus)	217 °C			
Reflow	Time (min to max) (t _L)	60 ~ 150 seconds			
Peak Tempo	Peak Temperature (T _P)				
Time of within 5 °C of Acti	Time of within 5 °C of Actual Peak Temperature (t _P)				
Ramp-do	6 °C / second max.				
Time from 25 °C to	8 Minutes max.				
Do Not	260 °C				



Packaging Information

Part Number	Package	Quantity	Packaging Option		
SPCL1-XXXX	SPCL Package	56 PCS / Inner Box	Bulk		
SPCL1-XXXX-12	SPCL Package	12 PCS / Inner Box	Bulk		





Usage

- 1.TVS must be operated in the specified ambient temp.
- 2.Do not clean the TVS with strong polar solvent such as ketone, esters, benzene and halogenated hydrocarbon, to avoid damaging the encapsulating layer.
- 3.Please do not apply severe vibration, shock or pressure to TVS, to avoid element cracking.

Replacement

- 1.If TVS is visually damaged, please replace it.
- 2.TVS is a non-repairable product. For safety sake, please use equivalent TVS for replacement.

Storage

- 1.Storage Temp. Range: (-55 to 150) °C.
- 2.Do not store the TVS at the high temp., high humidity or corrosive gas environment, to avoid influencing the solder- ability of the lead wires. The product shall be used up within 1 year after receiving the goods.

Environmental Conditions

- 1.TVS should not be exposed to the open air, nor direct sunshine.
- 2.TVS should avoid rain, water vapor or other condition of high temp. and high humidity.
- 3.TVS should avoid sand dust, salt mist, or other harmful gases.

Max. Typical Capacitance of TVS

The typical capacitance of TVS is listed in the specifications. Designers may refer to it when designing TVS in High frequency circuit.

Installation Mechanical Stress

- 1.Do not knock TVS when installing, to avoid mechanical damage.
- 2. Please do not apply severe vibration, shock or pressure to TVS, to avoid surface resin or element cracking.